

ZP3400 - RECTIFIER DIODE

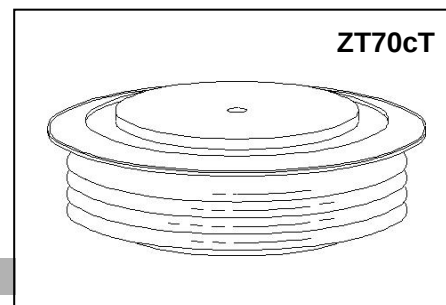
Shanghai Sunco Electronics Co., Ltd.

1800-2400V_{RRM}

GENERAL PURPOSE HIGH POWER STANDARD RECTIFIER

Features:

- . All Diffused Structure
- . High Surge rating
- . Blocking capability up to 2400 volts
- . Ceramic Housing Hermetic Package
- . Pressure Assembled Device



ELECTRICAL CHARACTERISTICS AND RATINGS

Reverse Blocking

Device Type	V _{RRM} (1)	V _{RSM} (1)
ZP3400-18	1800	2000
ZP3400-20	2000	2200
ZP3400-22	2200	2400
ZP3400-24	2400	2600

V_{RRM} = Repetitive peak reverse voltage

V_{RSM} = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	I _{RRM}	5 mA 90 mA (3)
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Notes:

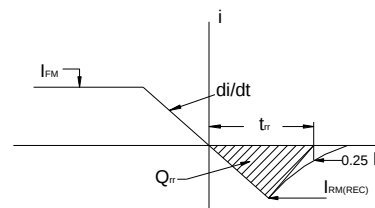
All ratings are specified for T_j=25 °C unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range 0 to +175 °C.

(2) 10 msec. max. pulse width

(3) Maximum value for T_j = 175 °C.

(4) See parameter definition below:



REVERSE RECOVERY CHARACTERIST

Conducting - on state

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average forward current	I _{F(AV)}		3400		A	Sinewave, 180°, T _c =100 °C
RMS forward current	I _{FRMS}		5338		A	Nominal value
Peak one cycle surge (non repetitive) current	I _{FSM}		40800		A	10 msec (50Hz), sinusoidal wave-shape, 180° conduction, T _j = 175 °C
I square t	I ² t		8.3 × 10 ⁶		A ² s	10 msec
Peak forward voltage	V _{FM}		1.25		V	I _{FM} = 3000A;T _j =25°C
Threshold voltage	V _{FO}		0.8		V	T _j =175°C,I=0.5 π I _{F(AV)} to 1.5 π I _{F(AV)}
Slope resistance	r _F		0.09		mΩ	T _j =175°C,I=0.5 π I _{F(AV)} to 1.5 π I _{F(AV)}
Reverse Recovery Current (4)	I _{RM(REC)}				A	I _{FM} = 500 A; di/dt = -10 A/s;T _{jmax}
Reverse Recovery Charge (4)	Q _{rr}			5000	μC	I _{FM} = 500 A; di/dt = -10 A/s;T _{jmax}
Reverse Recovery Time (4)	t _{rr}				μs	I _{FM} = 500 A; di/dt = -10 A/s;T _{jmax}

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T_j	-40	+175		°C	
Storage temperature	T_{stg}	-40	+175		°C	
Thermal resistance - junction to case	$R_{\theta(j-c)}$		0.0125		°C/W	Double sided cooled
Thermal resistance - case to heatsink	$R_{\theta(c-s)}$		0.004		°C/W	Double sided cooled
Mounting force	P	30	37	33	kN	
Weight	W			0.85	kg.	

* Mounting surfaces smooth, flat and greaseless

CASE OUTLINE AND DIMENSIONS